

Quantum Simulations with Ion Traps

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Introduction to Quantum Simulations

The Problem (posed by Feynman 1982)

Quantum systems are exponentially complex:

40 spin $\frac{1}{2}$ systems need $2^{40} \times 2^{40} = 10^{24}$ coefficients

Present calculations are limited:

Deterministic algorithms: 32 spins

Non-deterministic algorithms: 100 x 100 spins

*Classical computer,
distressed physicist*



*Quantum simulator,
happy physicist*



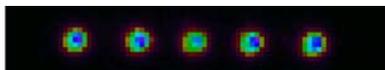
The Solution

(proposed by Feynman and revisited by Lloyd 1992)

Simulate on another multi-body quantum system

Trapped ions map onto condensed matter paradigms
(realized separately by Cirac, Milburn, 2004)

Trapped ions more ideal than real materials

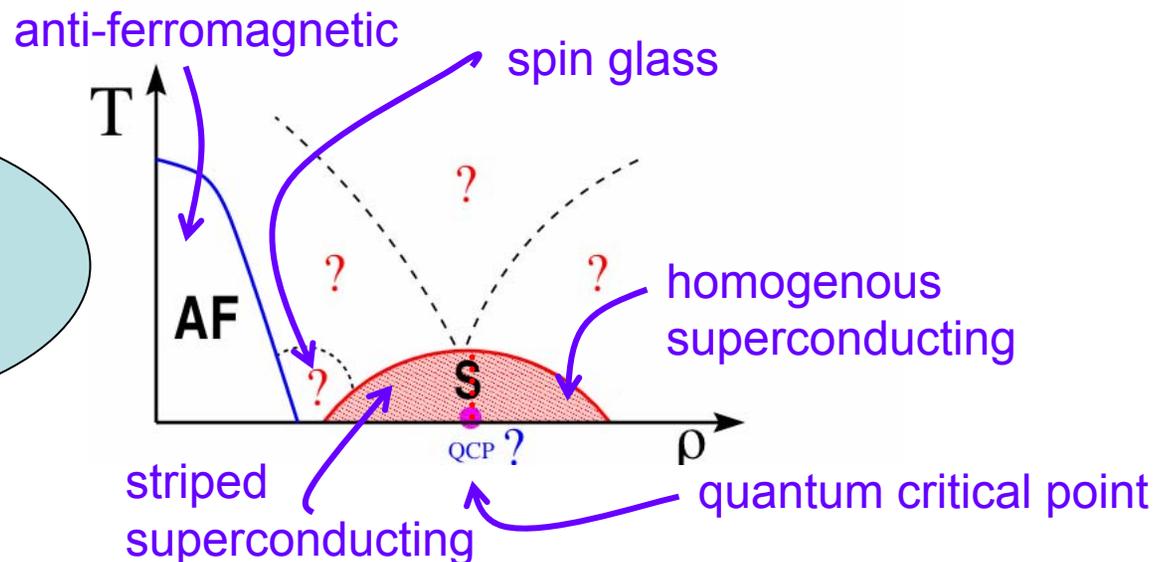


No, really, it's a problem

Current computational capabilities limit understanding of many systems

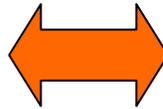
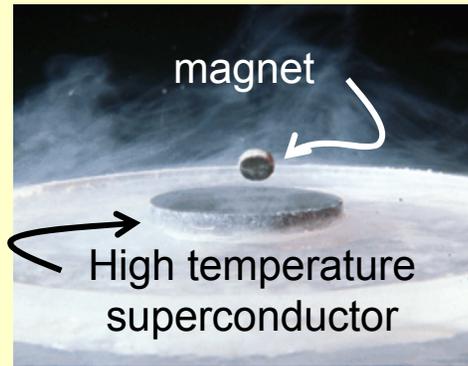
- Understanding and designing new materials with unprecedented properties
 - High T_c superconductivity, cuprates
 - Superconducting Pu compounds, heavy fermions
 - ...
- Finite Density QCD: what is the proton size, etc.?
- Large-N nuclei: for $N > 12$ approximations become unreliable
- Large molecules

Complex, uncertain
phase diagram
of a new material

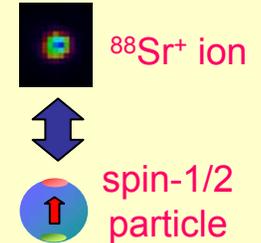
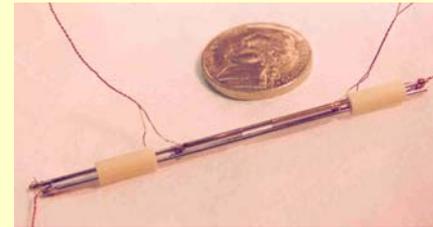


What is a Quantum Simulator?

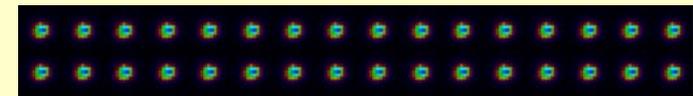
Real physical system
we don't understand
(e.g. high T_C superconductor)



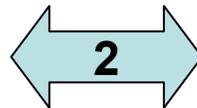
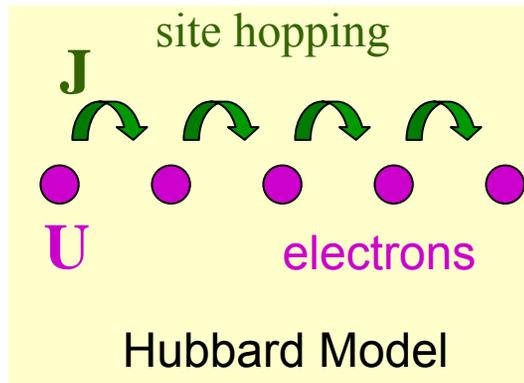
Tightly controlled system



Proposed
ion array w
laser forces

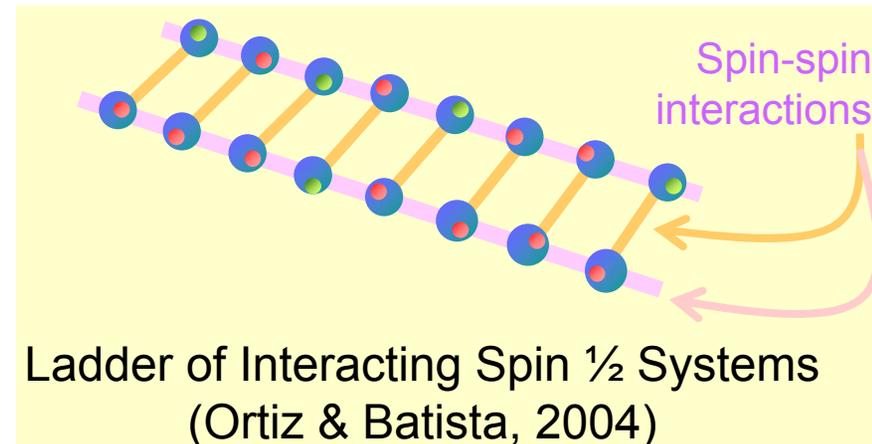


Propose a particle model
we can't fully explore



Jordan-Wigner
transformation
to a spin model

Trapped ions and laser forces
simulate a spin model we can control



Relation to Quantum Computing

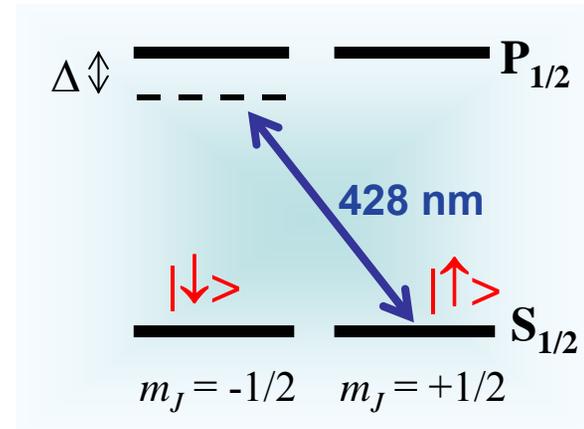
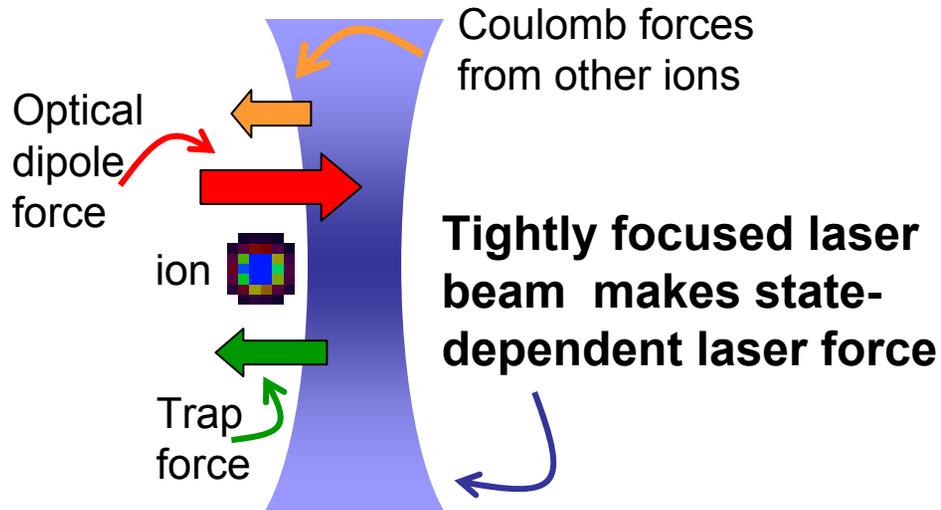
Both need:

**Good state initialization
Long decoherence times
Good final state readout
Serious engineering capabilities**

BUT they are different:

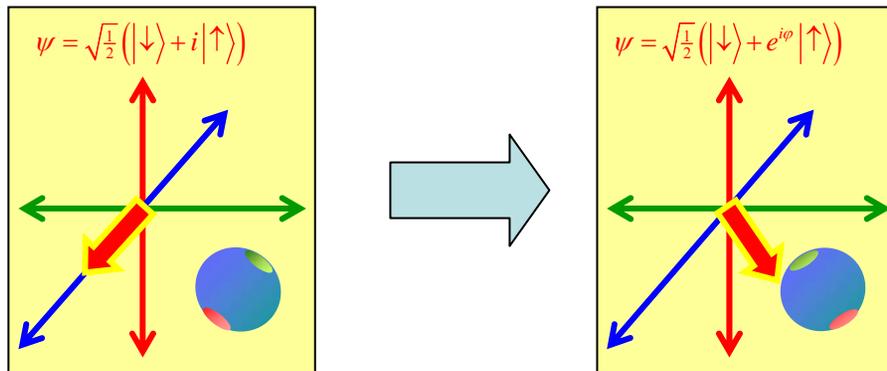
Quantum Computer	Quantum Simulator
Universal	Configured for one particular problem (we will do materials science problems)
Need universal gates	Don't need universal gates
Scaleable set of individually addressed qubits	Don't need individual addressing
Stringent timing requirements	Continuous interactions

Physics of Ion Trap Quantum Simulators



Ion moves through potential due to trap fields and *other moving ions*

$|\uparrow\rangle$ state accumulates phase



Bloch vector

State-dependent,
neighbor-dependent
rotation of Bloch vector

Expect spin-spin interactions

Transformation to Heisenberg Model

Porras & Cirac, PRL 2004

Lab Hamiltonian

State-selective optical dipole force along α

Real or simulated magnetic field

$$H = \sum \hbar\omega_n a_{n,\alpha}^\dagger a_{n,\alpha} + F^\alpha q_\alpha \left| \uparrow \right\rangle \left\langle \uparrow \right|_i^\alpha + B^\alpha \sigma_i^\alpha$$

Trap and ion potential

$$q_\alpha \propto (a_{n,\alpha}^\dagger + a_{n,\alpha})$$

Transform Lab Hamiltonian into Simulated Hamiltonian

$$H' = e^{-S} H e^S$$

where

$$S = \sum \eta_{n,i}^\alpha (1 + \sigma_i^\alpha) (a_{n,\alpha}^\dagger - a_{n,\alpha})$$

Simulated Hamiltonian (terms up to η^2)

Small if $\eta \sim F \sqrt{1/\hbar m \omega^3} \ll 1$

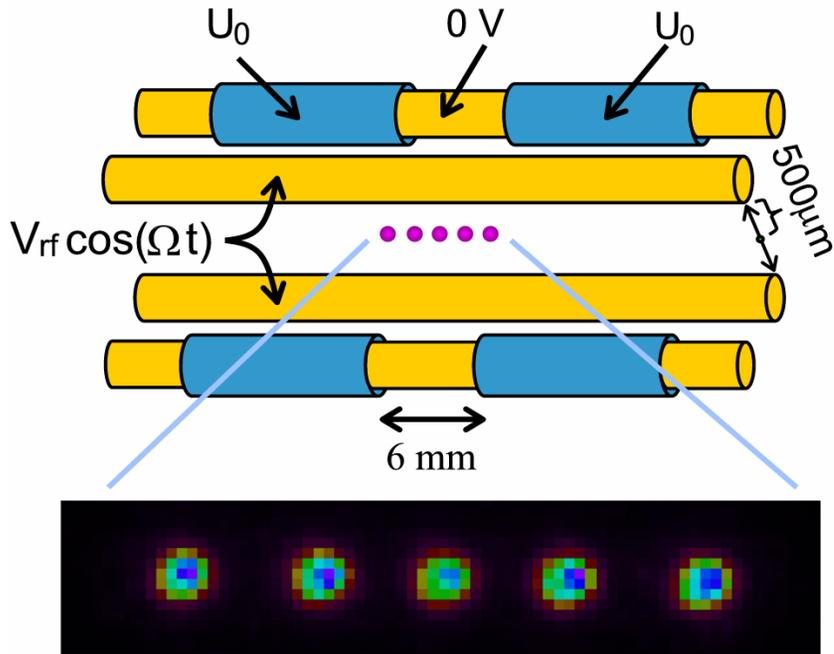
$$H' = \sum \hbar\omega_n a_{n,\alpha}^\dagger a_{n,\alpha} - J_{i,j}^\alpha \sigma_i^\alpha \sigma_j^\alpha + B'^\alpha \sigma_i^\alpha + \varepsilon$$

Exchange interaction $J_{i,i+1} \propto F^2$

Old B plus effective field

Macroscopic Linear rf Trap

Confine ions radially in a time-averaged potential and axially with a static potential:

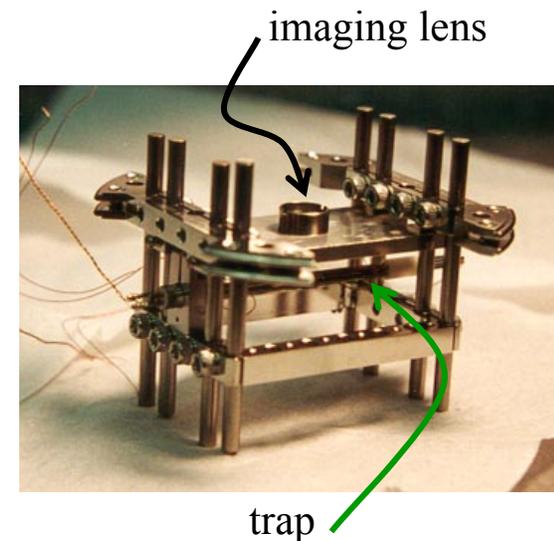
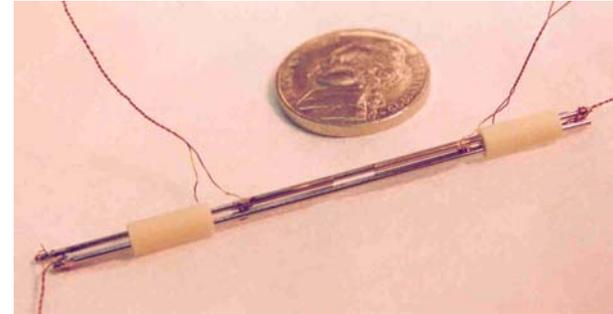


(resonant 422-nm light scattered from 5 ions)

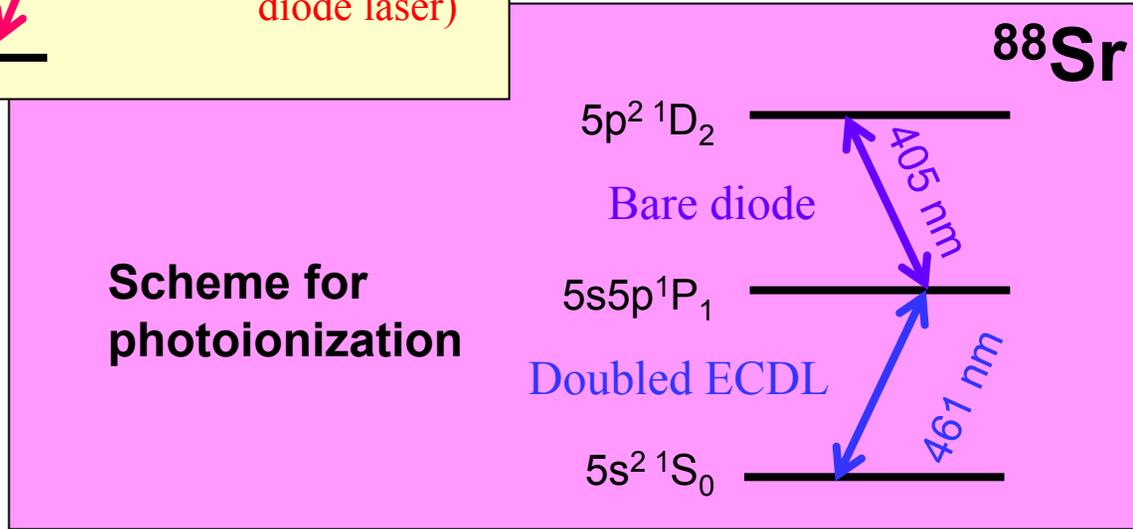
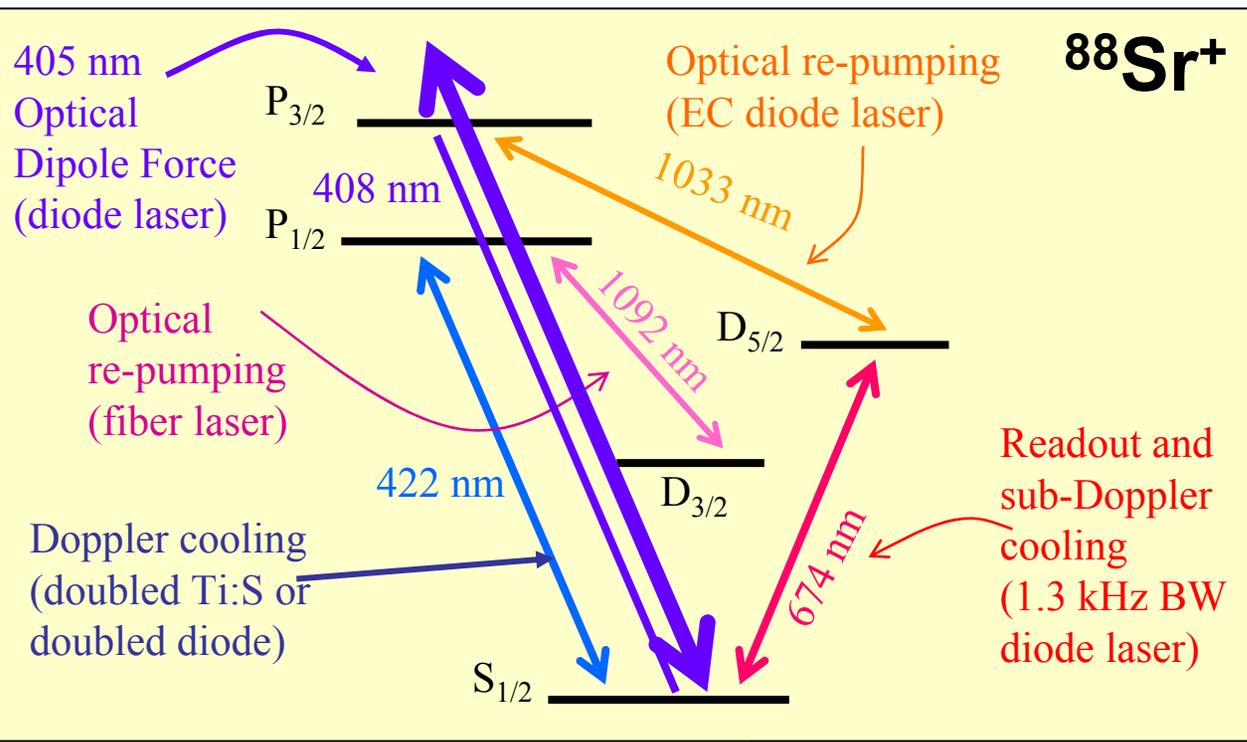
Trap depth ~ 25 eV

($\omega_{radial} \sim 2 \pi 2$ MHz, $\omega_{axial} \sim 2 \pi 400$ kHz)

Ion lifetime > 1 day



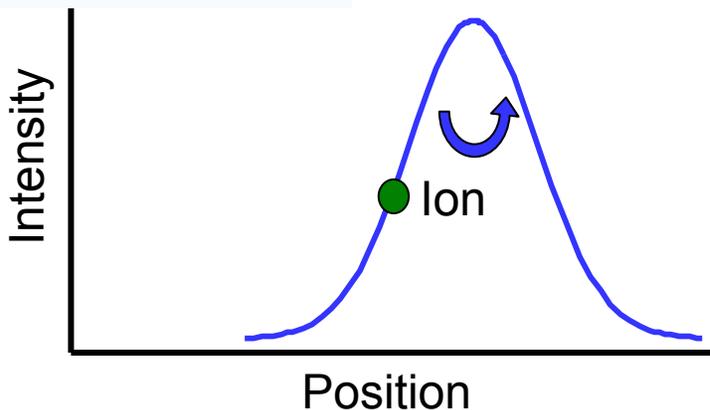
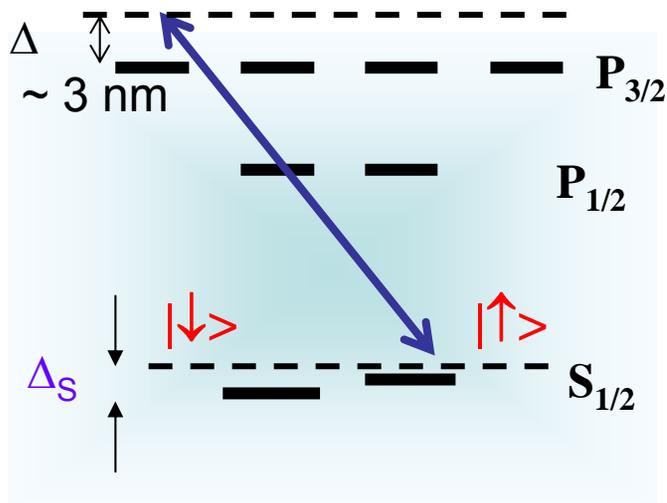
Strontium 88



Balancing AC Stark Shifts

AC Stark shifts Δ_s are HUGE (\sim MHz)!

Acts like a giant B-field

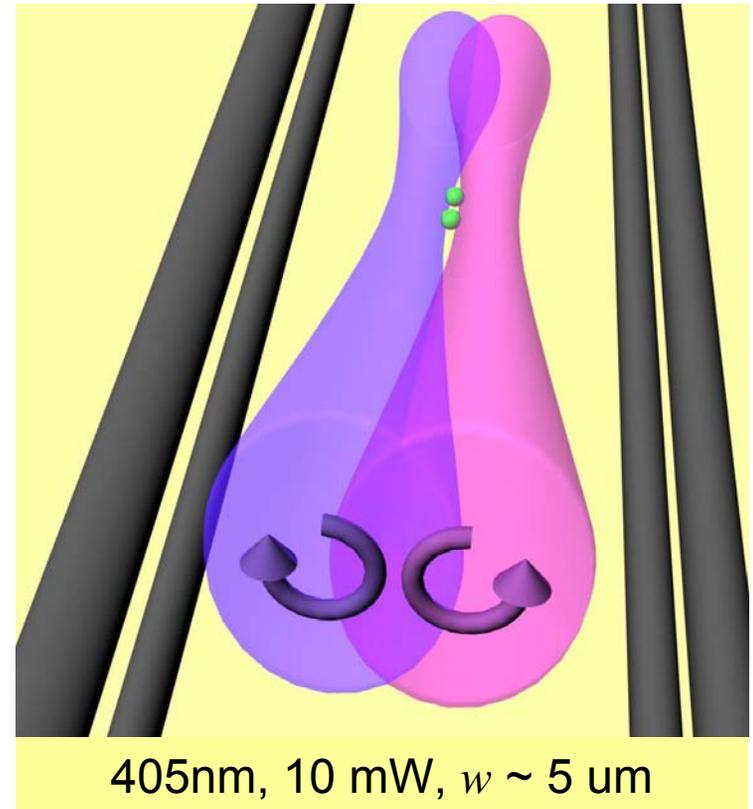
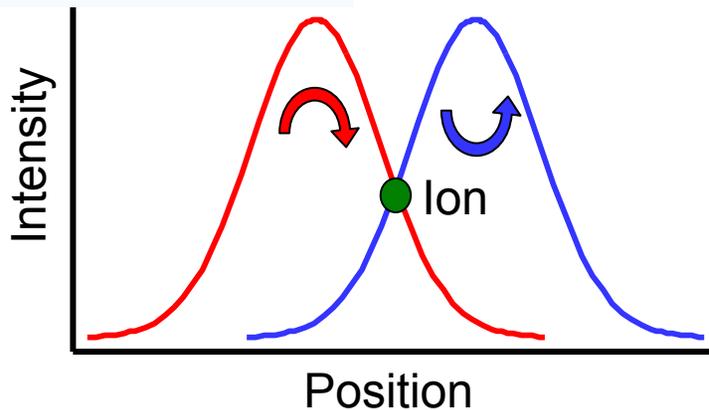
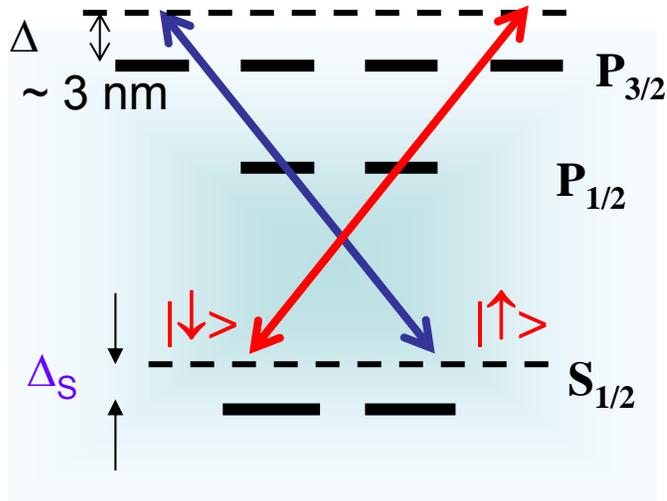


Balancing AC Stark Shifts

AC Stark shifts Δ_s are HUGE (\sim MHz)!

Acts like a giant B-field

Solution: equal (but large) shifts for \uparrow and \downarrow

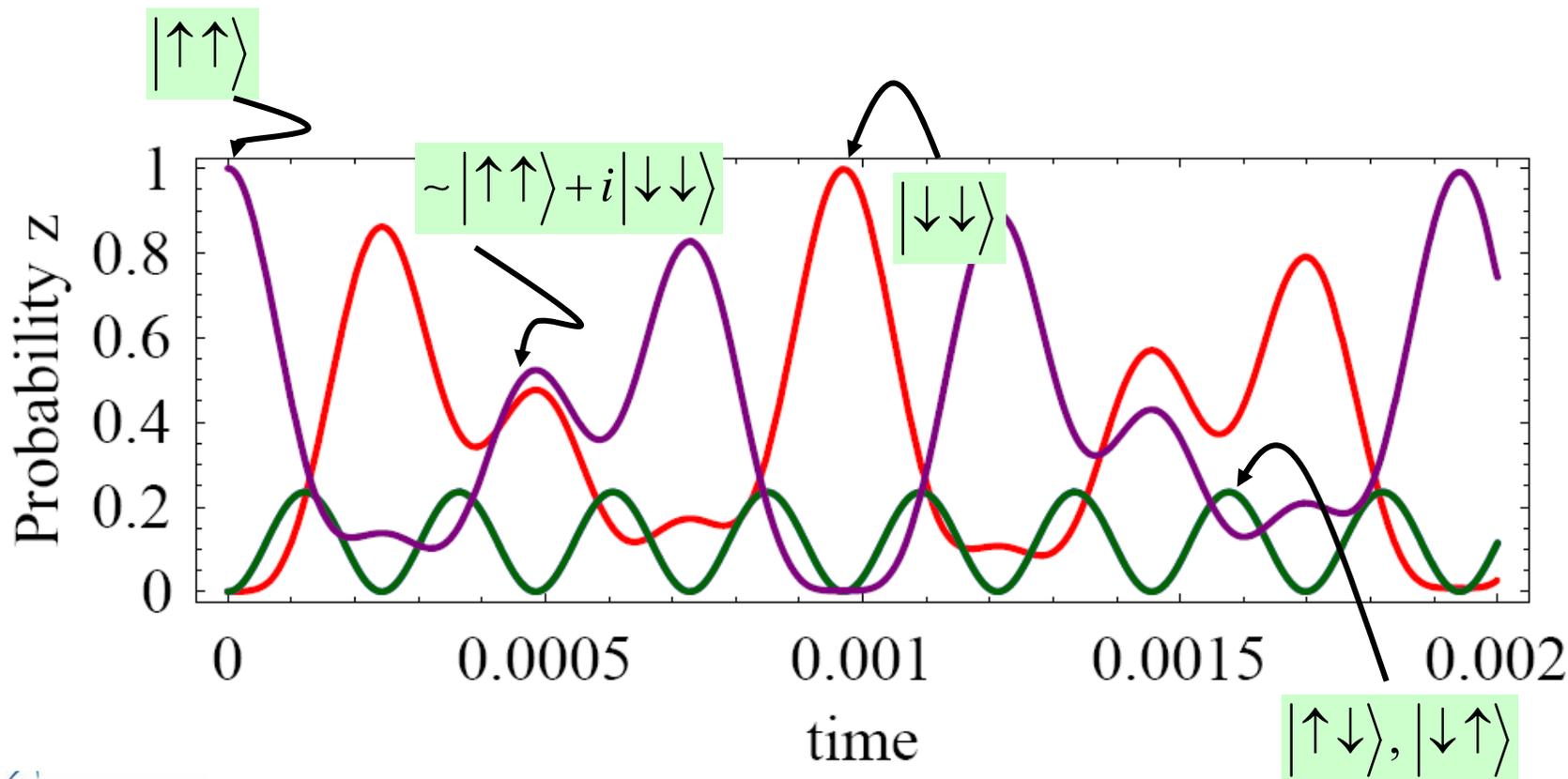


Expected Behavior

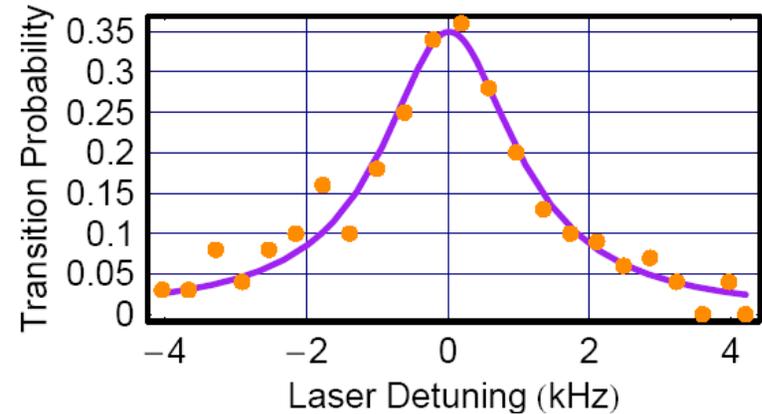
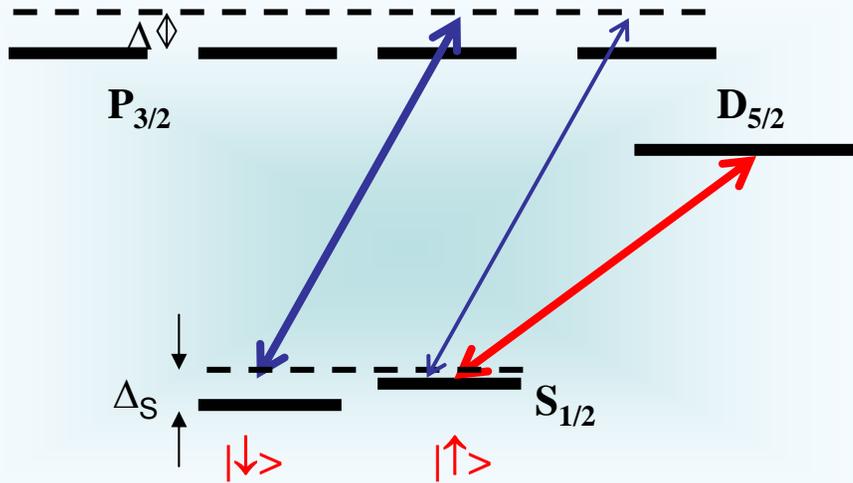
Expected results for 2-spin Ising model

Optical dipole force along one direction and equal for both ions

$$J_z/2\pi = 1000 \text{ Hz}; \quad B_x/2\pi = 1 \text{ kHz}$$



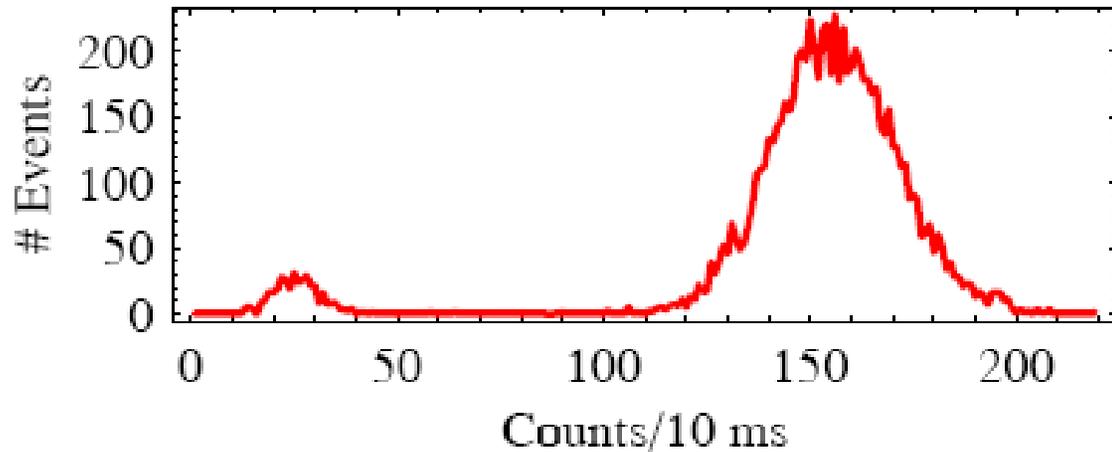
State Measurement



Leave on only one dipole force beam to break $\downarrow \uparrow$ degeneracy

Shelve \uparrow state into "dark" state with precisely tuned red laser

No scattered blue light if ion is in D state



Ions v Ising model (single well)

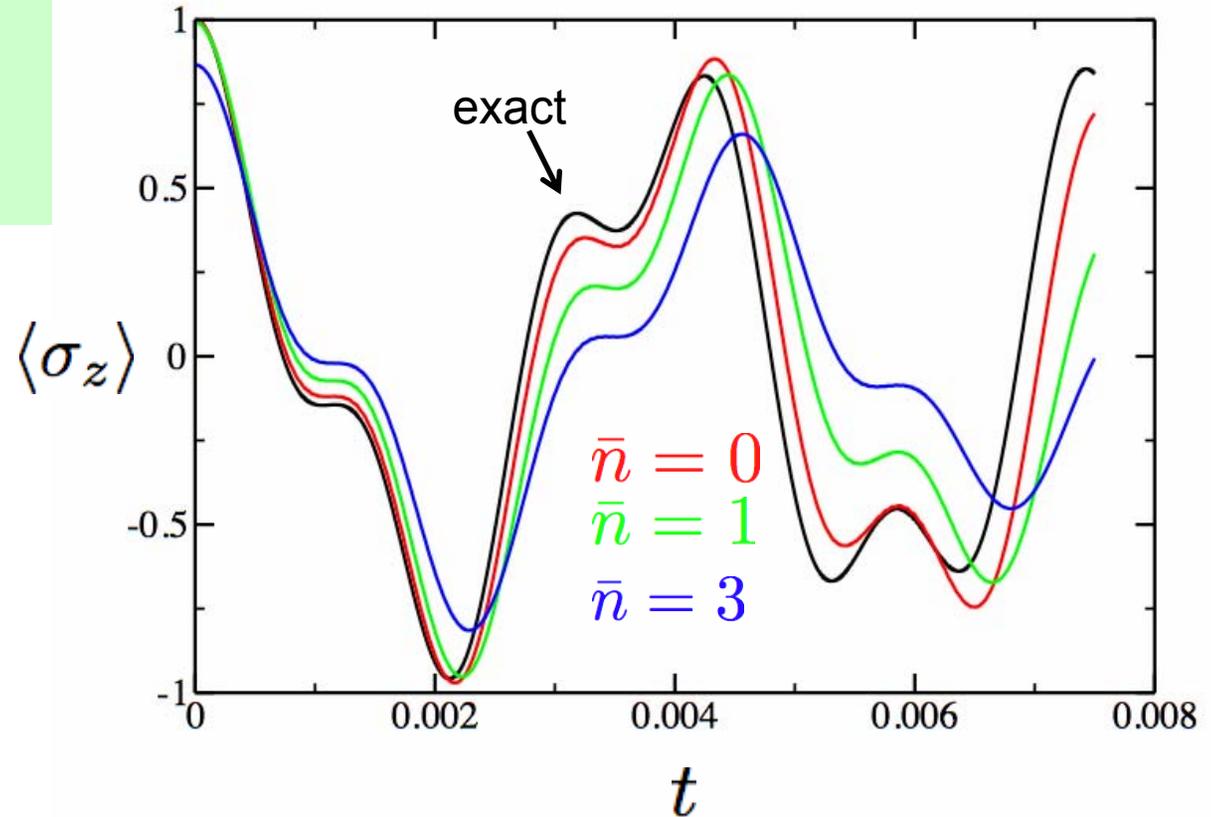
- Calculate 2-ion state for
- Laser forces along axial direction
 - Total of 7 phonon states in each mode

Plot $P_{\uparrow\uparrow} - P_{\downarrow\downarrow}$ v time

$\eta \sim$
displacement /
 $|n = 0\rangle$ width

$$\eta = 0.06$$

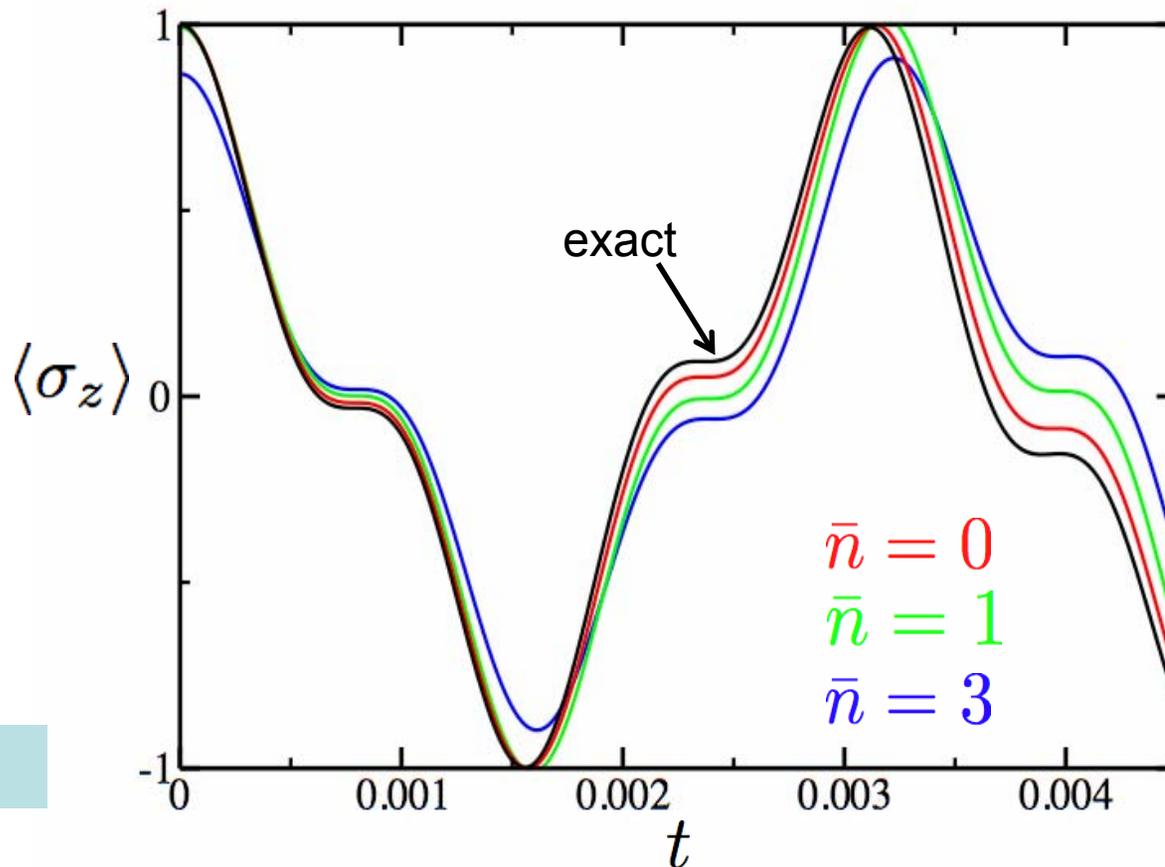
$$\omega_{cm} = 100 \text{ KHz} \quad B \approx -J \approx 1.3 \text{ KHz}$$
$$F = 25 \times 10^{-24} \text{ N}$$



Need to cool ions to near ground state of motion

Ions v Ising model (double well)

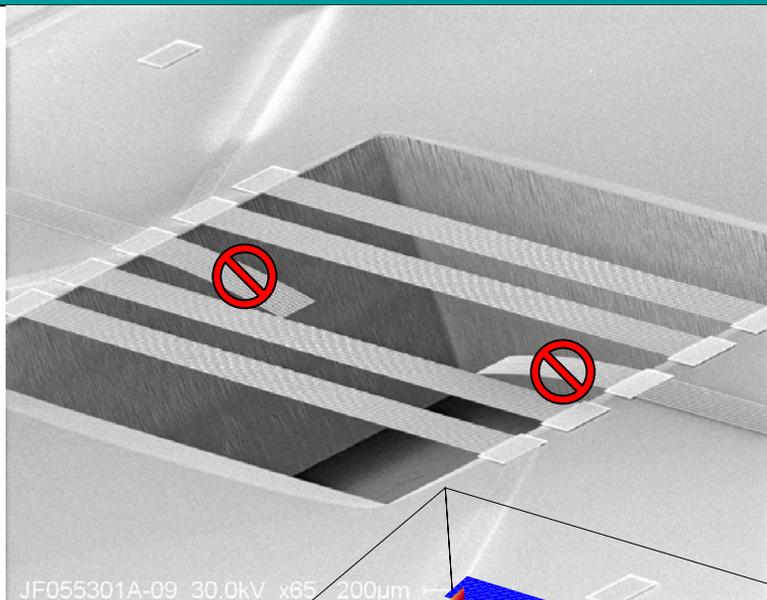
$$\begin{aligned} \omega_{cm} &= 100 \text{ KHz} & F &= 25 \times 10^{-23} \text{ N} & d &\approx 20 \mu\text{m} \\ \omega_{br} &= 128 \text{ KHz} & B \approx -J &\approx 1.8 \text{ KHz} \end{aligned}$$



$$\eta = 0.06$$

Reduced error for double well with closely-spaced ions

First microfabricated trap



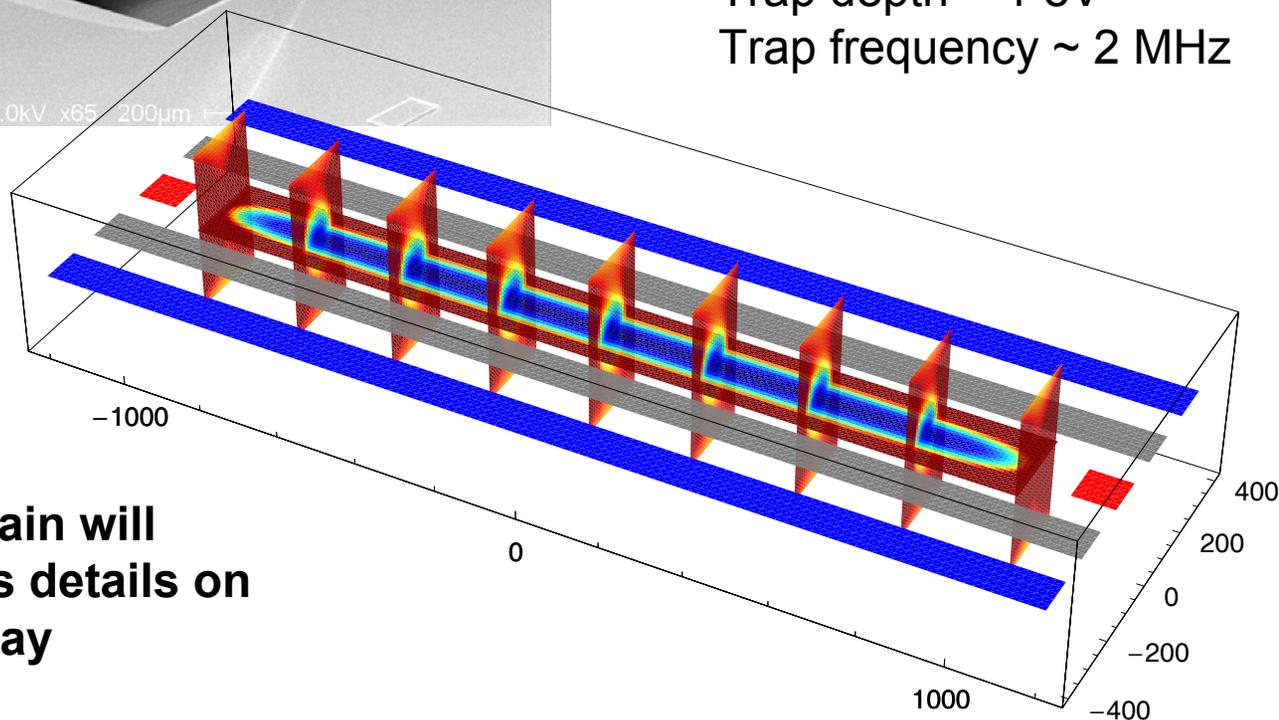
Electrode thickness ~ 3 microns
width ~ 80 microns
length ~ 2 mm

Au-coated on top and bottom

For 200V, 20 MHz drive, 1V on endcaps:

Trap depth ~ 1 eV

Trap frequency ~ 2 MHz



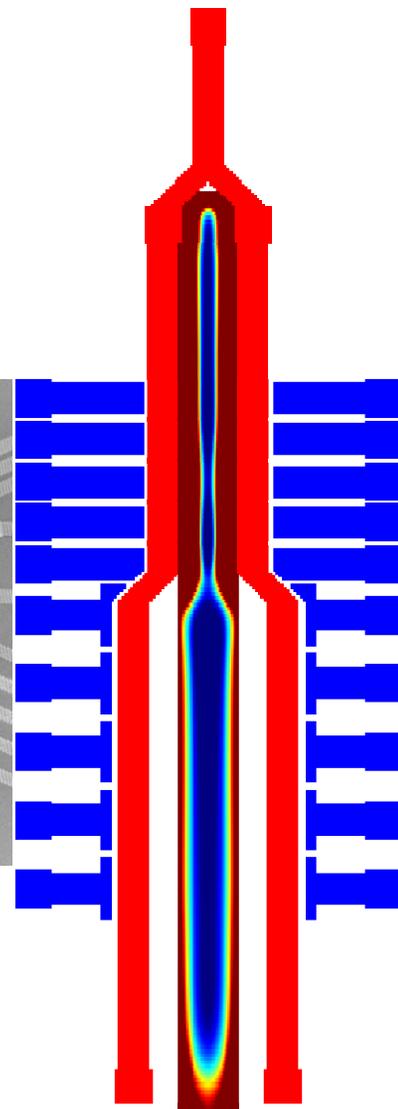
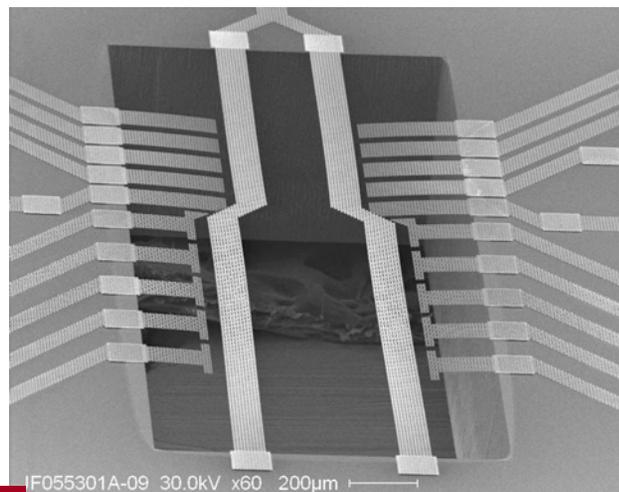
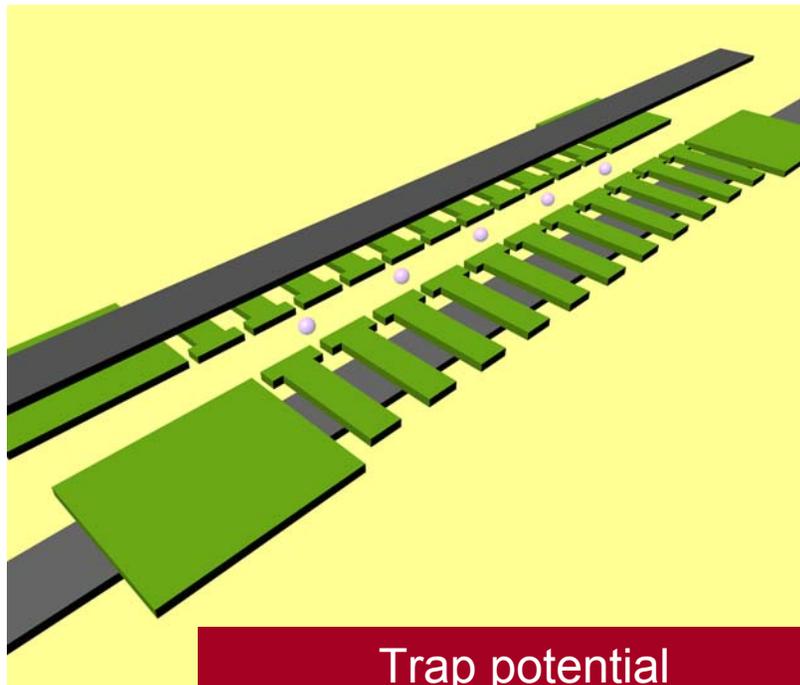
**Matt Blain will
discuss details on
Thursday**

Next traps

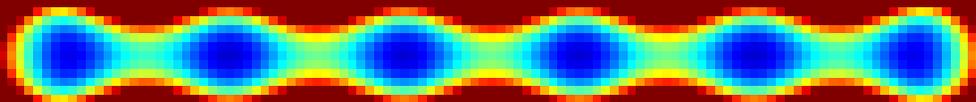
Need segmented traps with 10 μ m DC electrode spacing

Correspondingly small rf electrode spacing

First test with dual zone trap (larger loading zone)



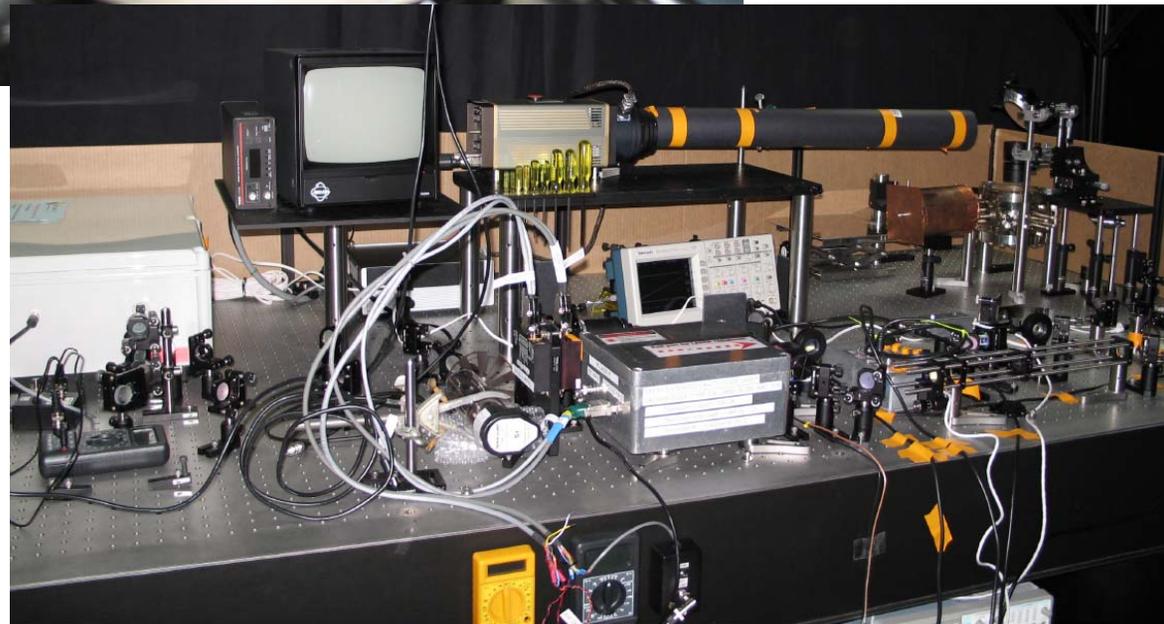
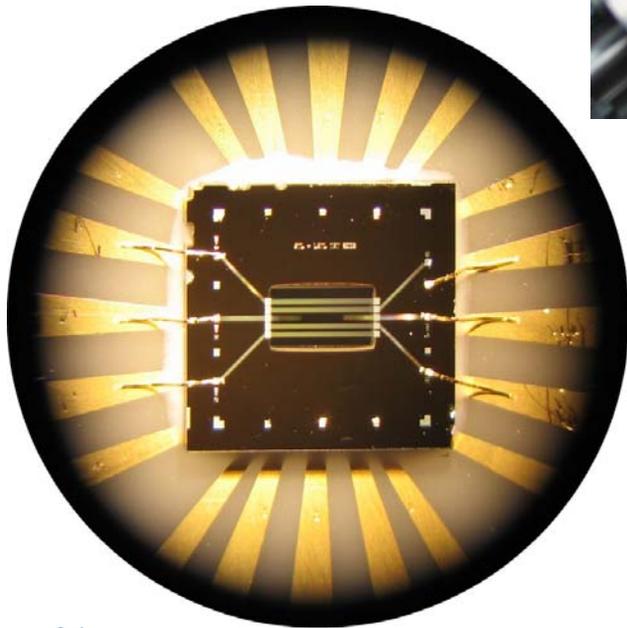
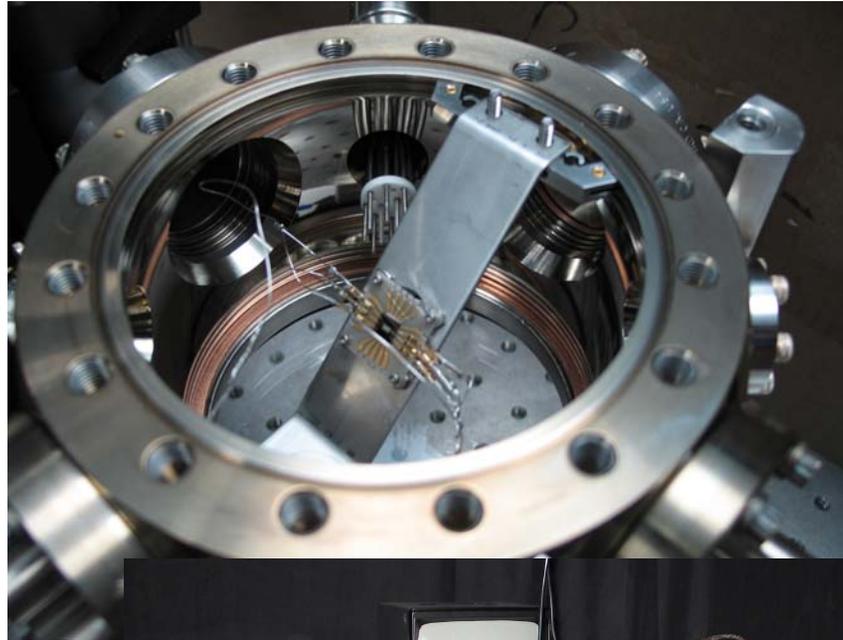
Trap potential



Microfabricated ion traps in the (2nd) lab

Have set up:

- Cooling lasers
- Imaging system
- Vacuum system
- RF system
- etc.



Summary

Trapped ions can simulate quantum condensed matter systems

Quantum simulators are sort of like analog quantum computers

Have the basic building blocks for small simulations

- optics that reduce AC Stark shifts

- laser systems for sub-Doppler cooling

Building with Sandia advanced, scaleable traps for large simulations

See also posters by Kendra Vant and Rolando Somma